

Flux Pinning in MgB_2 :

What do we want?
How might we get it?



Lance Cooley, Valeria Braccini, Jeff Waters,
Peter Hellenbrand, Ben Senkowicz, Satyabrata
Patnaik, Xueyan Song, Jianyi Jiang, Chang-Beom
Eom, Eric Hellstrom, and David Larbalestier

Applied Superconductivity Center
University of Wisconsin

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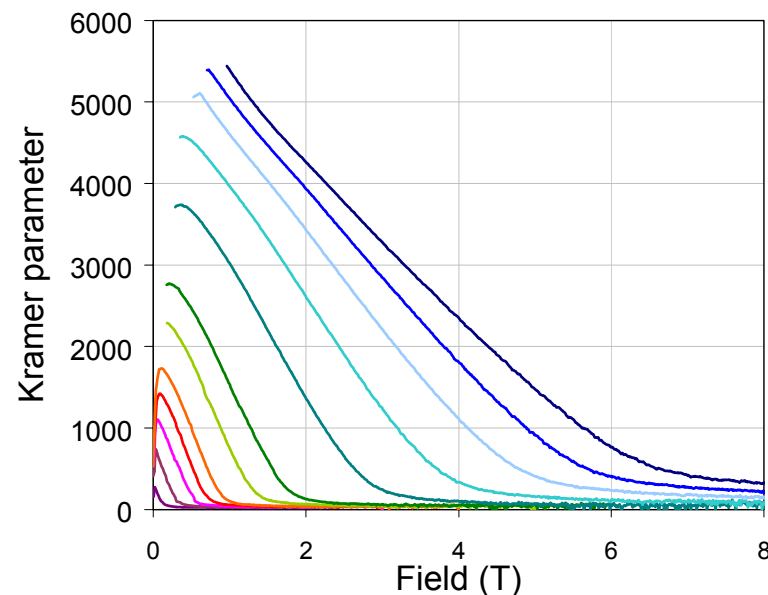
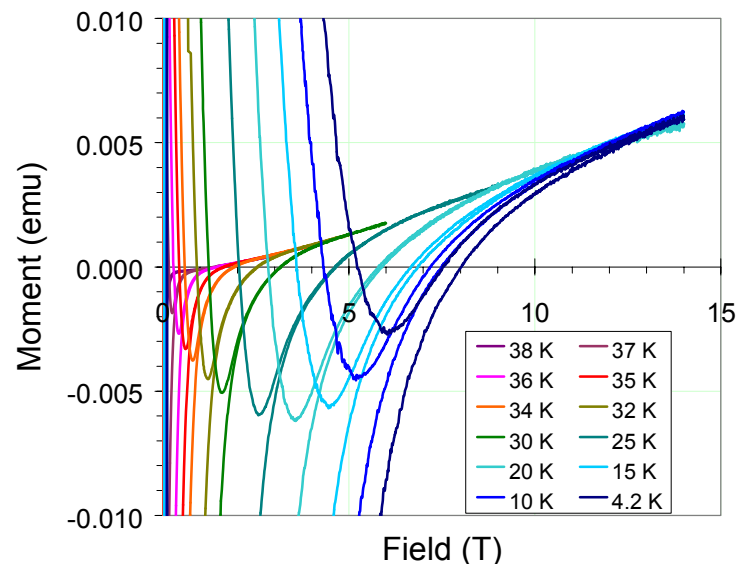
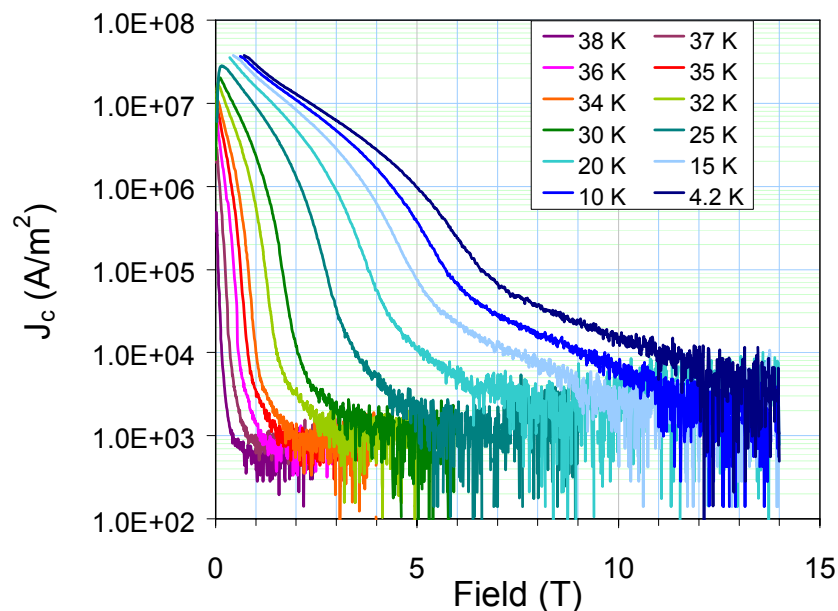
BOROMAG, 17-19 June 2002



Grain-boundary pinning indicated early on

- Linear Kramer plots over wide temperature range
 - Tails due to anisotropy and percolative connection of grains oriented with $H \parallel ab$

Early 2001 Princeton bulk



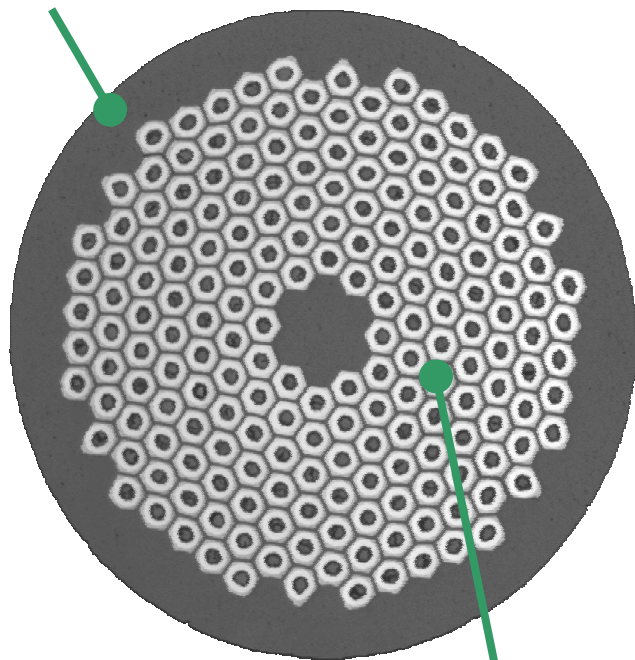


What do we want? – Clues from Nb_3Sn

Powder-In-Tube Conductor from ShapeMetal Innovation (SMI), Holland

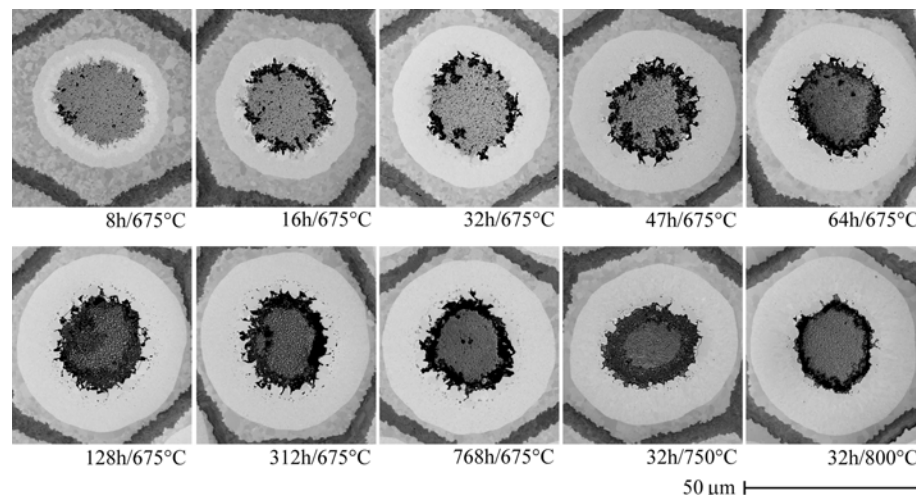
- Very uniform multifilamentary strand cross-section
- Longitudinally homogeneous
- Radial gradients of Sn
 - But gradient falls steeply only near Nb/ Nb_3Sn interface
- Small grains, ~140 nm diameter

0.90 mm Diameter Wire



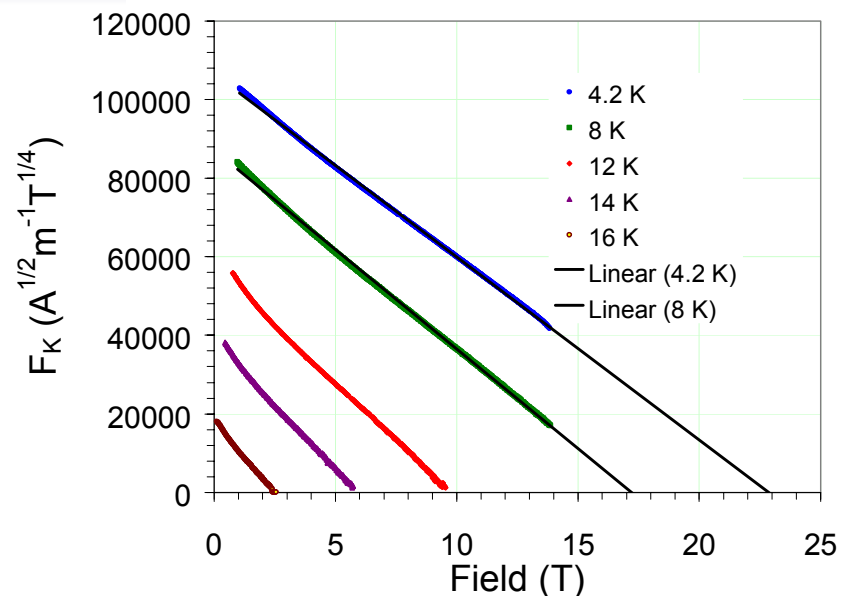
192 Nb or Nb_{7.5}Ta filaments
with NbSn₂ powder core

Nb_3Sn Layer grows radially



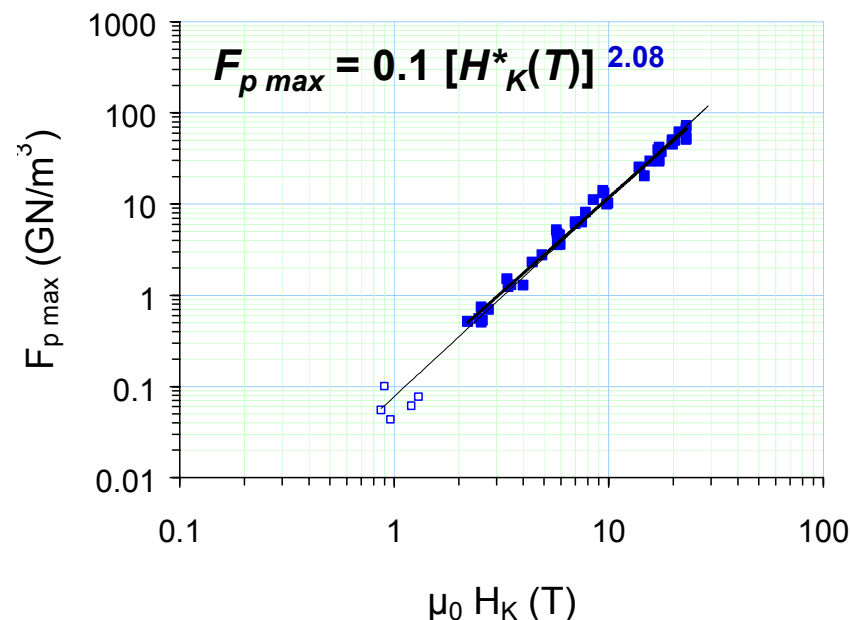
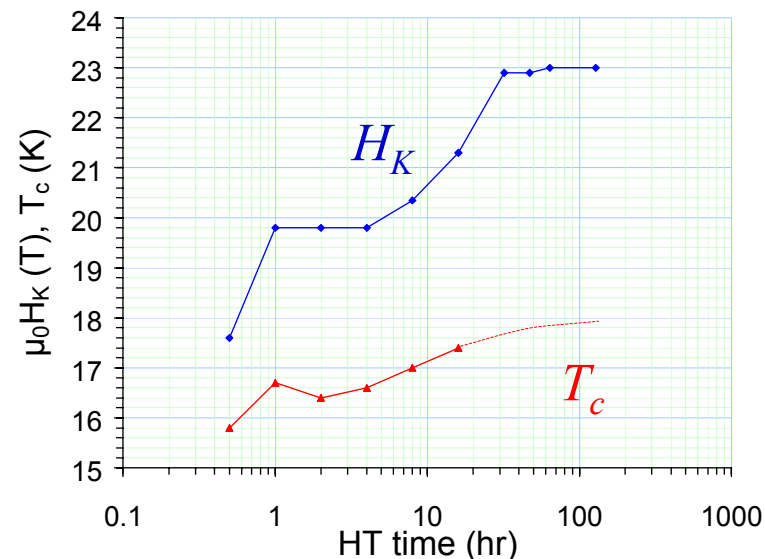


Homogeneous properties are essential



- If tin content varies by as little as **0.3%**, resultant variations of T_c , $H_{c2}(4.2K)$, $H^*(4.2K)$ cause **$F_{pmax}(4.2K)$ to decrease by 10%** and **$F_p(4.2K, 12T)$ to drop 18%**

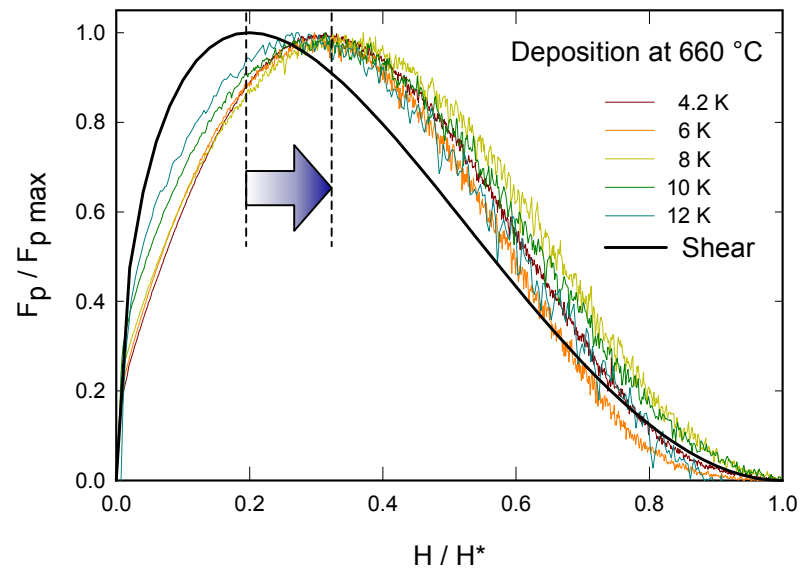
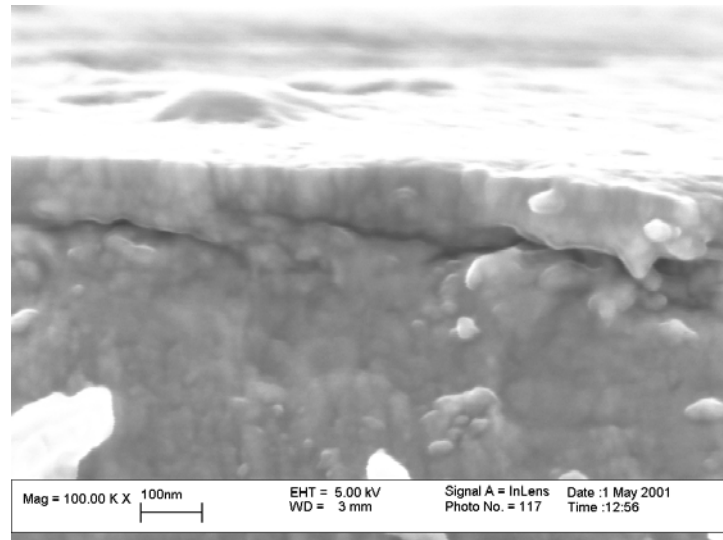
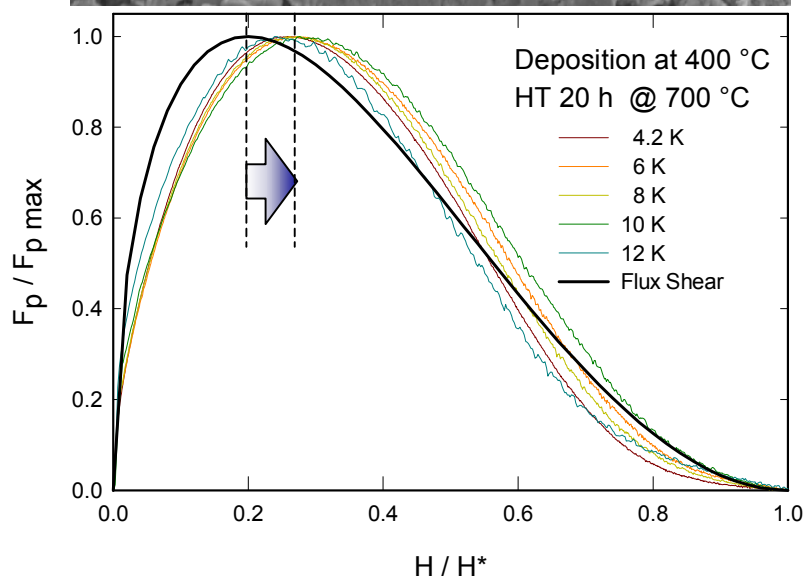
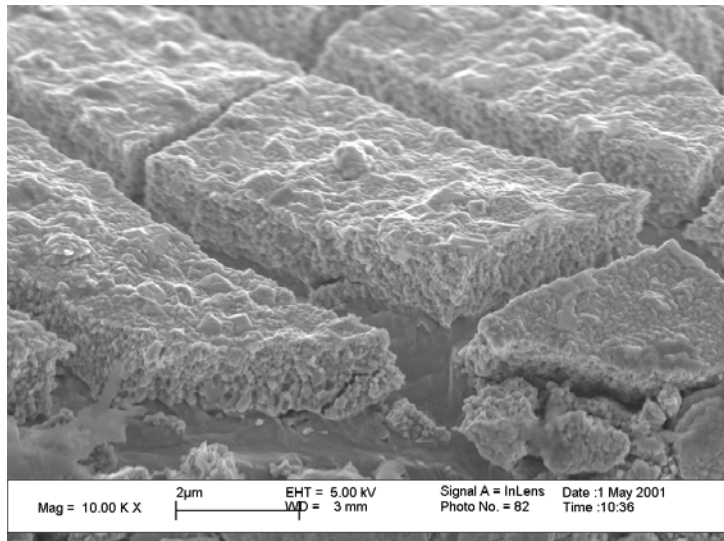
Assumed: $T_c = 17.6K$; $H_{c2}(4.2K) = 30T$;
 $H^*(4.2K) = 24T$; linear variations of $T_c(\%Sn)$
 and $H_{c2}(T)$





Improved high-field pinning for $D \sim a_0$

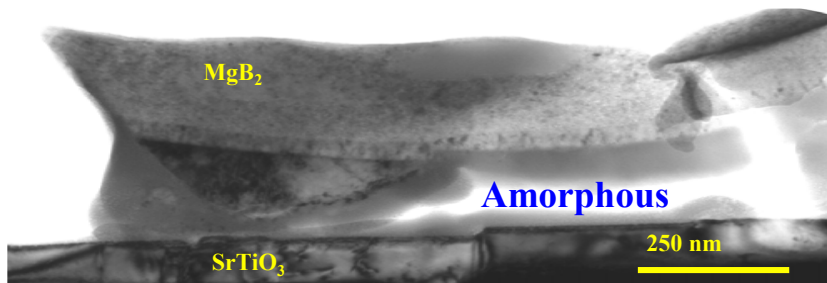
L D Cooley and P J Lee – *IEEE Trans ASC* 11, 3820 (2001)



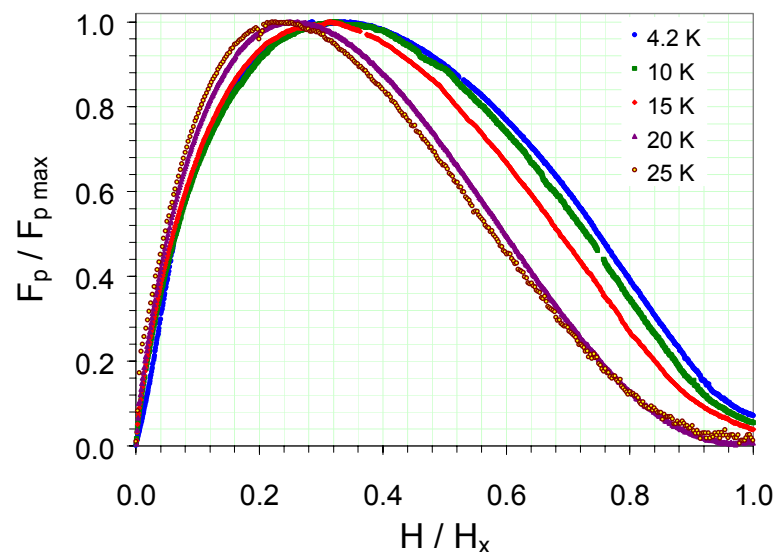
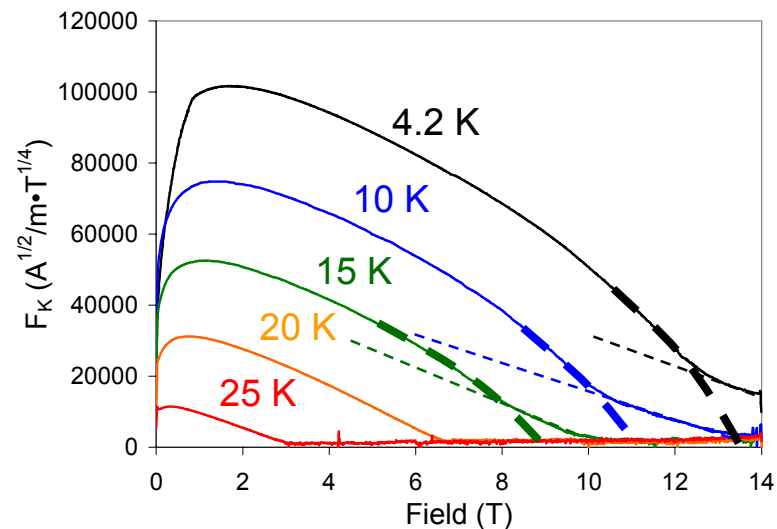


Pinning added at high fields in 1st generation MgB_2 films made by PLD

- Nanoscale grains, substantial MgO
- High field pinning:
 - Matrix of 5 nm MgB_2 grains with occasional 5 nm MgO grains
 - OR
 - Embedded MgO nanoprecipitates within MgB_2 grains



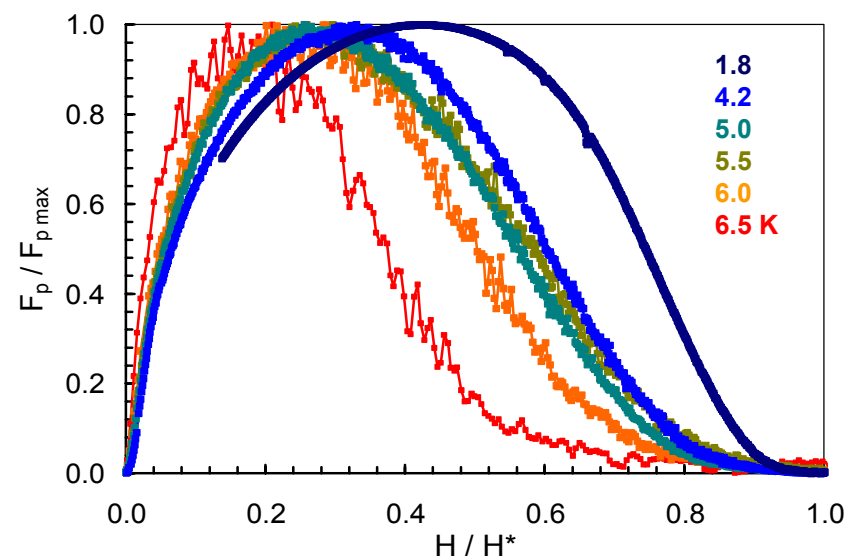
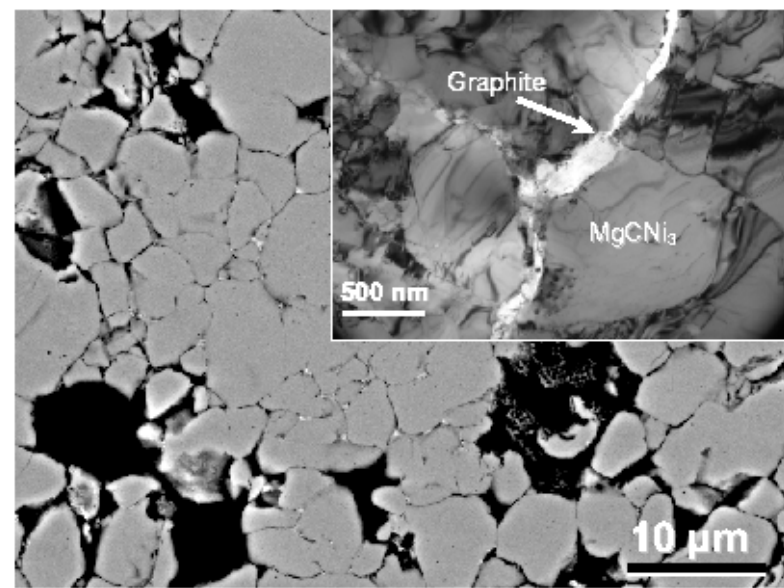
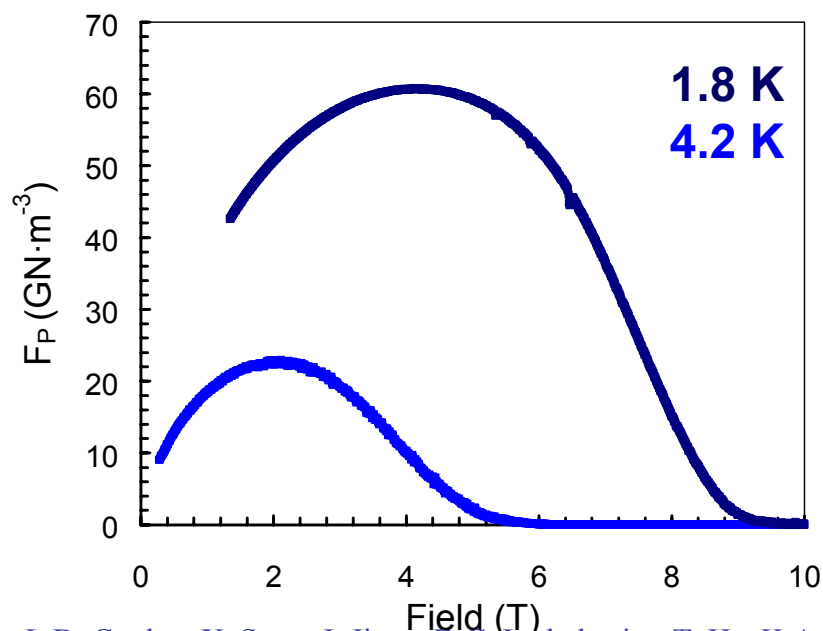
“Film 2”, C. B. Eom *et al.*, *Nature* **411**, 558 (2001)





MgCNi_3

- Very potent pinning sites indicated by $F_p(H)$ but not obvious in microstructure
- $F_p(H, T)$ like that of Nb-Ti — nanoprecipitates?

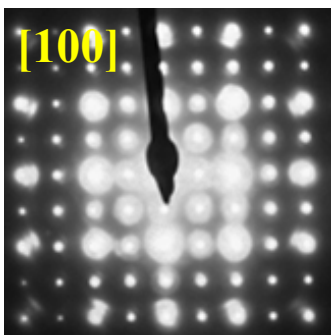
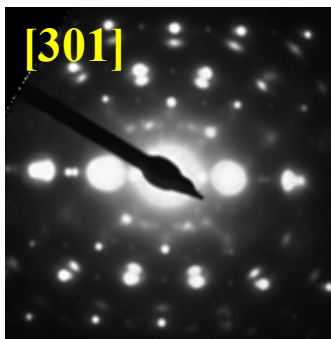
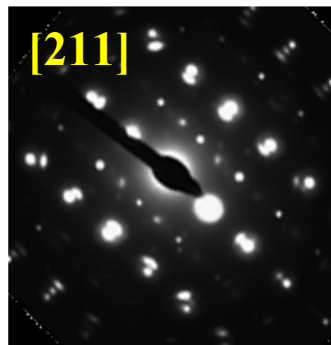


L.D. Cooley, X. Song, J. Jiang, D.C. Larbalestier, T. He, K.A. Regan, and R.J. Cava, *Phys. Rev. B* (to appear June 2002)

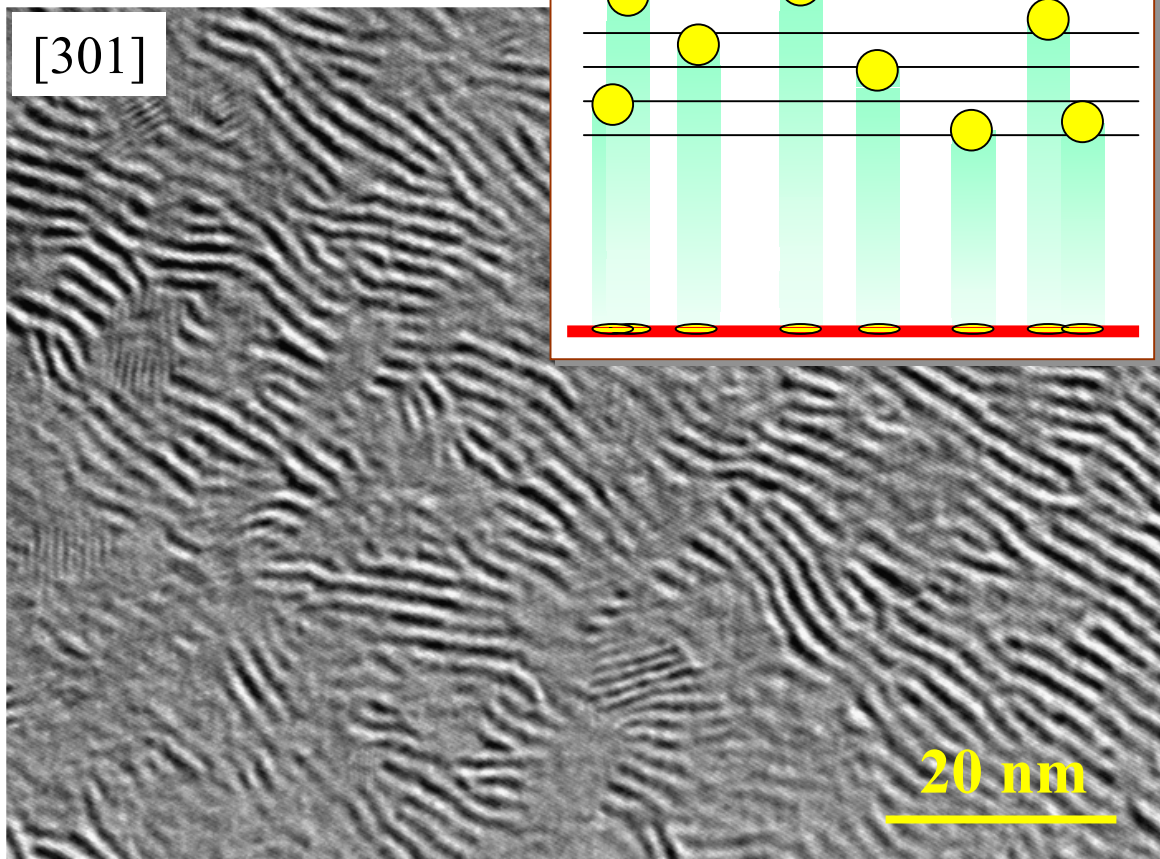


Intragranular nanoprecipitates in MgCNi_3

Diffraction from cubic precipitates



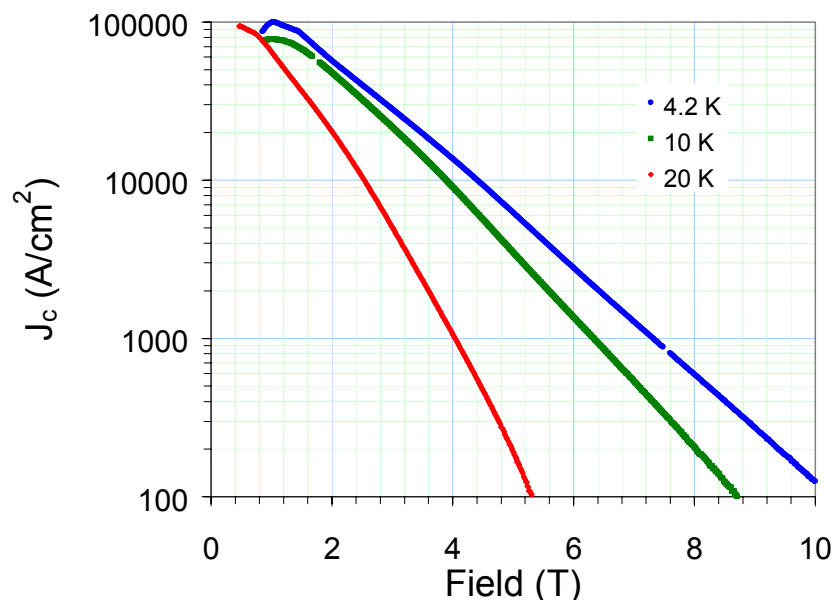
*Interference from cubic,
graphite precipitates*



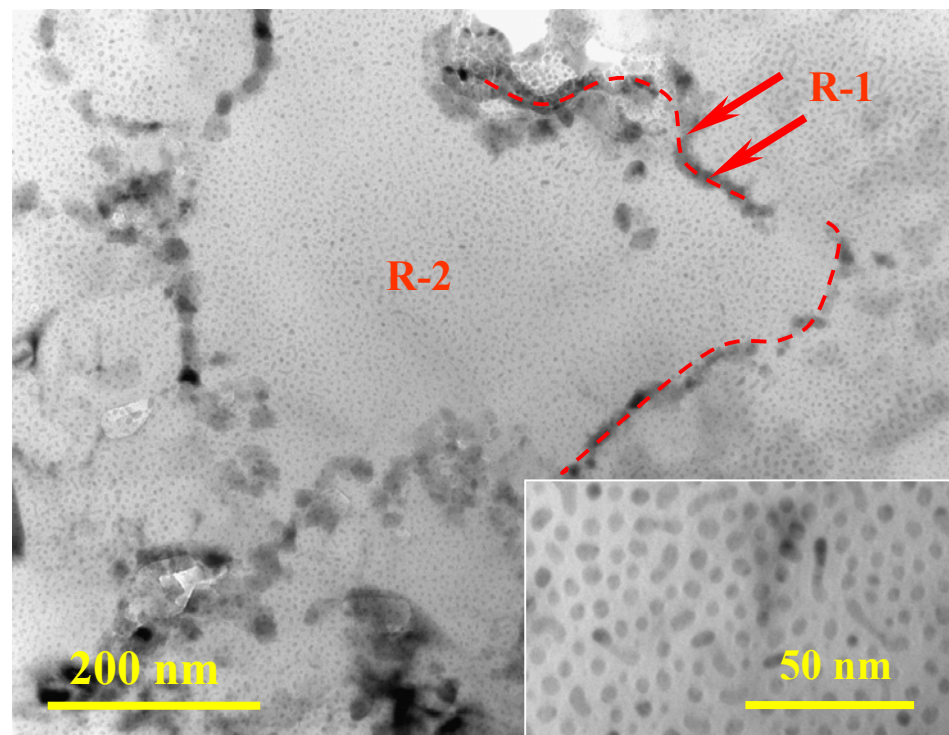


Nanoprecipitation by oxide $\leftrightarrow$ boride exchange in MgB_2

- Mg + B powders + 10wt.% Y_2O_3 nanoparticles
- XRD: YB_4 nanoprecipitates ($\text{Y}_2\text{O}_3 + 4 \text{MgB}_2 \rightarrow 2 \text{YB}_4 + 3 \text{MgO} + \text{Mg}$)
- But YB_4 precipitates in GBs break up current pathways in magnetization!



J. Wang, Y. Bugoslavsky, L. Cowey, A. Berenov, A.D. Caplin, L.F. Cohen, J.L. MacManus Driscoll (Imperial College); L. D. Cooley, X. Song, D. C. Larbalestier (UW-ASC) – submitted to *Applied Physics Lett.*





Precipitation routes from low-stability borides (work in progress...)

Free energy (per B)

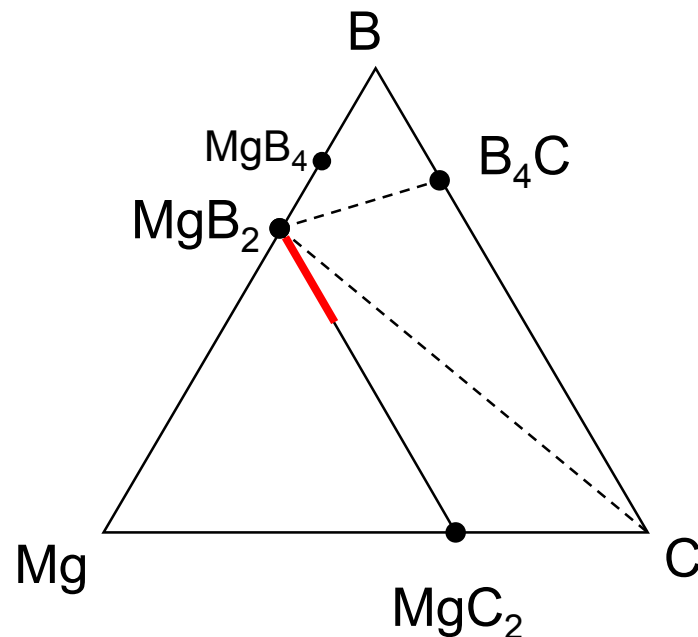
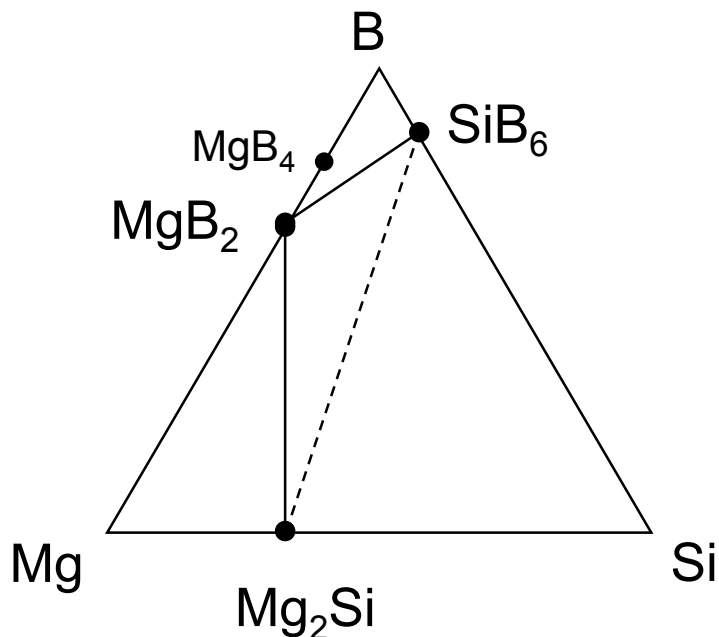
kJ/mol at 273 K

B_4C -13.82

SiB_6 -22.65

MgB_2 -25.43

- $5 Mg + SiB_6 \rightarrow 3 MgB_2 + Mg_2Si$
- $2.5 Mg + B_4C \rightarrow 2 MgB_2 + 0.5 MgC_2$
 $\rightarrow 2.5 Mg(B_{0.8}C_{0.2})_2$





Rapid synthesis of 37 K MgB_2 at 640-700 °C

Mg flakes + SiB_6 powder

1 h @ 640 °C

Phases by EDS, XRD

MgB_2 + Mg_2Si

Mg_2Si

Mg

Moment (emu)

0.000
-0.005
-0.010
-0.015
-0.020

Temperature (K)

30 32 34 36 38 40

Mg + SiB_6 powders

1 h @ 700 °C

20 μm

100 μm



Possible low-temperature synthesis of MgB_2 from SiB_6 ?

- 37 K transition even for 1 h @ 500 °C
- Ternary system fixes MgB_2 composition, T_c

Rogado et al, JAP 91:274 (2002)

Mg flakes + SiB_6 Powder

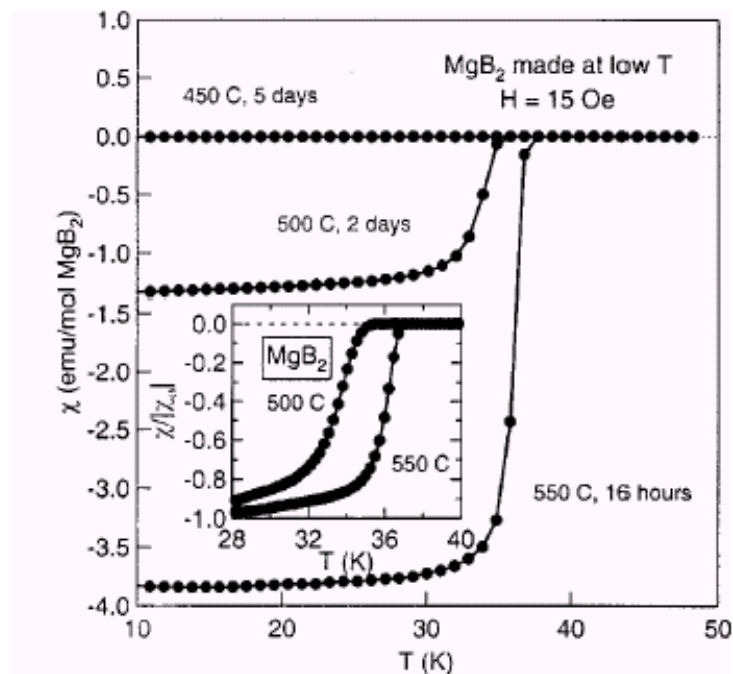
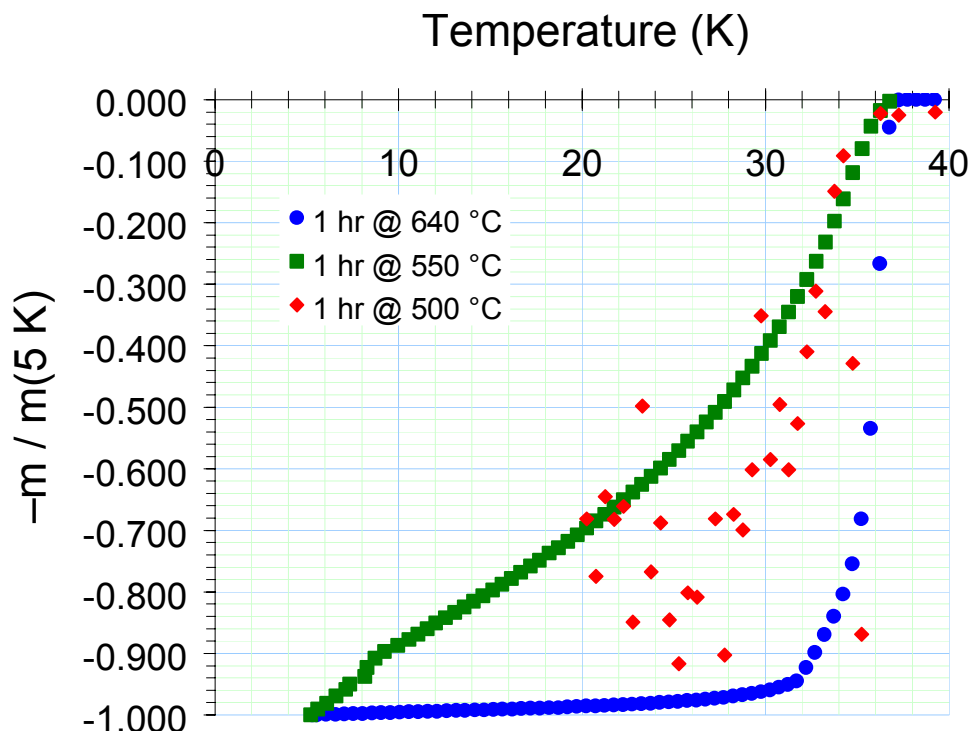


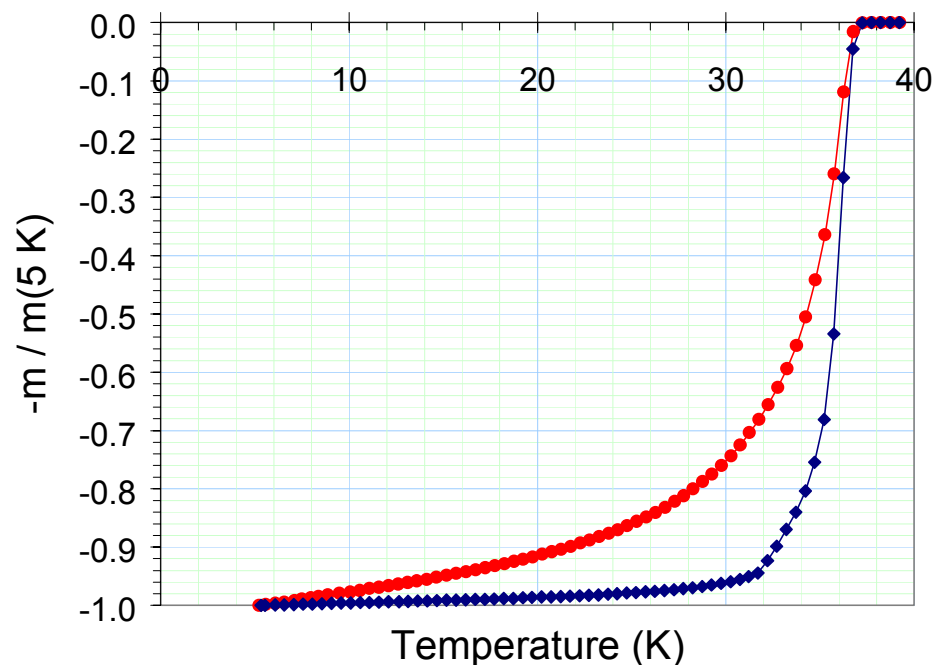
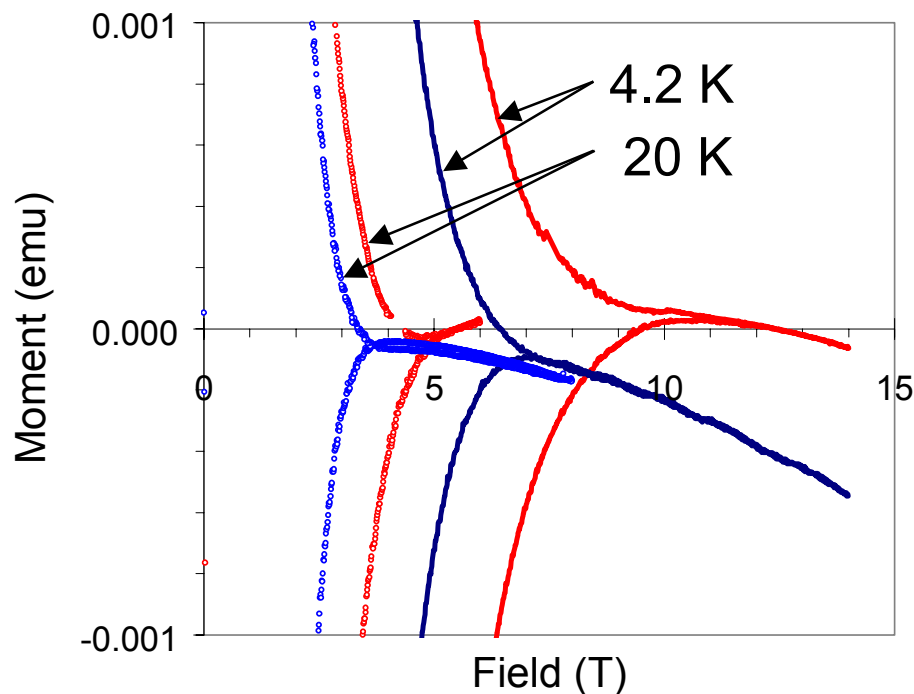
FIG. 2. Temperature dependent magnetization of polycrystalline powder samples of MgB_2 fabricated at different heating conditions. A 15 Oe dc field was applied after cooling in zero field. Inset shows detail of the region near T_c for the samples prepared at 550 and 500 °C.



Oxygen alloying from Mg powder?

- No evidence for Si alloying from XRD
- H^* higher for Mg powder, but same T_c

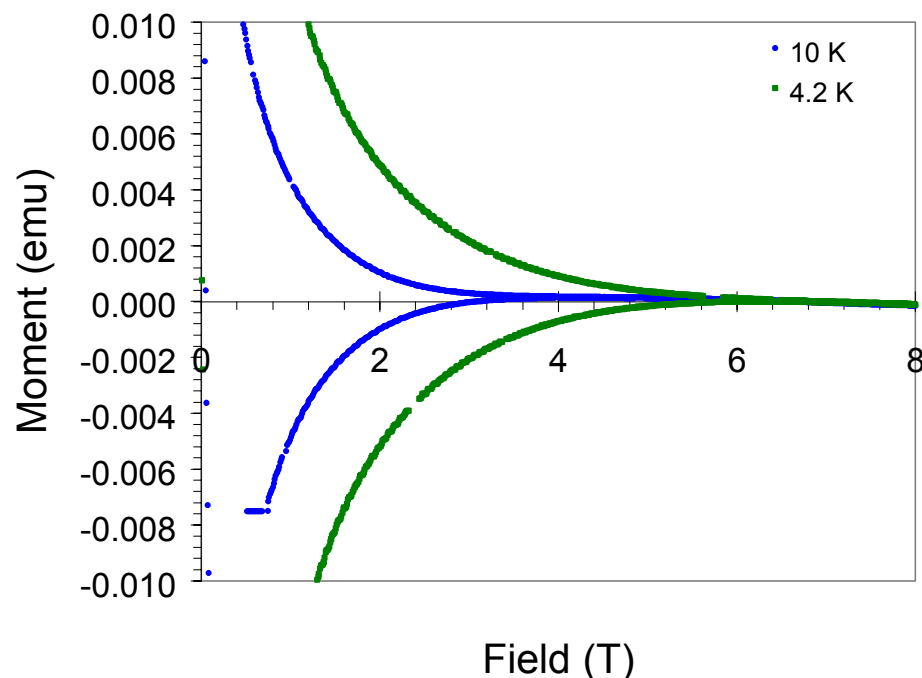
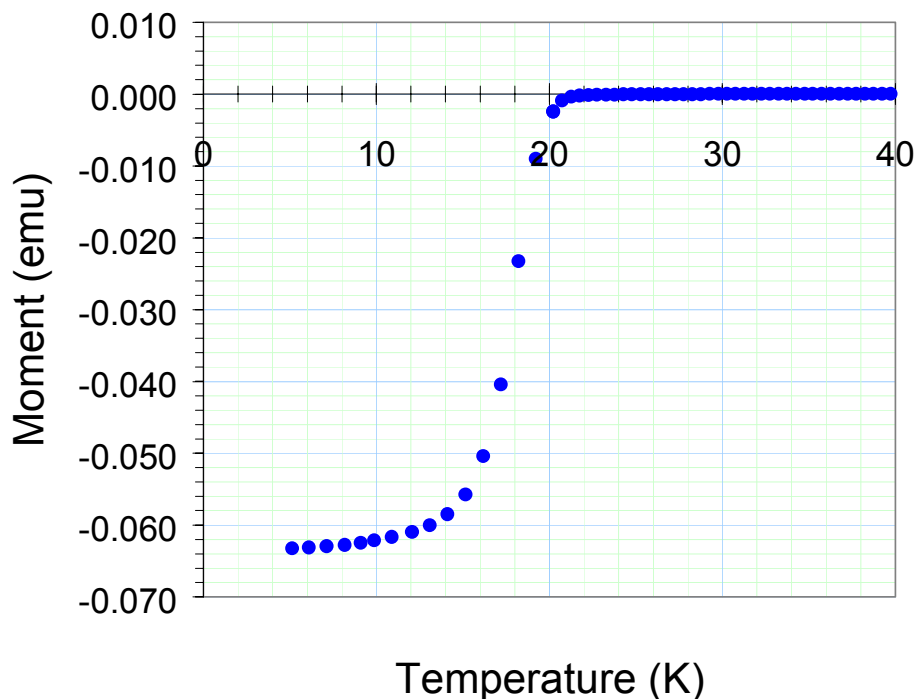
Mg **powder** + SiB₆ powder, 1h @ 700°C
Mg **flakes** + SiB₆ powder, 1h @ 700°C





$Mg + B_4C$

- Solid solution $Mg(B_{0.8}C_{0.2})_2$ after 1 hr @ 950°C indicated by T_c (Also Mickelson et al., PRB 65:052505)
- $dH^*/d\underline{T}$ slightly higher than that of MgB_2 , about -0.35 T/K





Conclusions

- Must get control at multiple levels
 - Microstructure (density, homogeneity)
 - Nanostructure (grain size, precipitation)
- There are opportunities for potent pinning sites
 - Nanoscale mixtures of grains
 - Intragranular nanoprecipitates
- Borides with lower free energy than MgB_2 show promise
 - $\text{Mg} + \text{SiB}_6$: low temperature reaction of nanopowder mixture possible?
 - $\text{Mg} + \text{B}_4\text{C}$: makes solid solution